

2SK3048

Silicon N-Channel Power F-MOS FET

■ Features

- Avalanche energy capacity guaranteed
- High-speed switching
- Low ON-resistance
- No secondary breakdown

■ Applications

- Contactless relay
- Diving circuit for a solenoid
- Driving circuit for a motor
- Control equipment
- Switching power supply

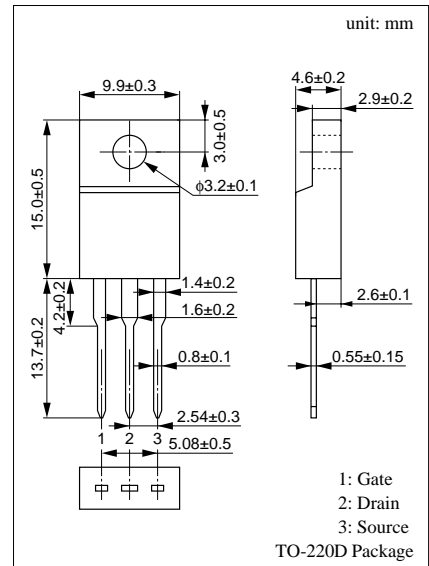
■ Absolute Maximum Ratings ($T_C = 25^\circ\text{C}$)

Parameter	Symbol	Ratings	Unit	
Drain to Source breakdown voltage	V_{DSS}	600	V	
Gate to Source voltage	V_{GSS}	± 30	V	
Drain current	DC	I_D	± 3 A	
	Pulse	I_{DP}	± 6 A	
Avalanche energy capacity	EAS*	22.5	mJ	
Allowable power dissipation	$T_C = 25^\circ\text{C}$	P_D	35	W
	$T_a = 25^\circ\text{C}$		2	
Channel temperature	T_{ch}	150	$^\circ\text{C}$	
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$	

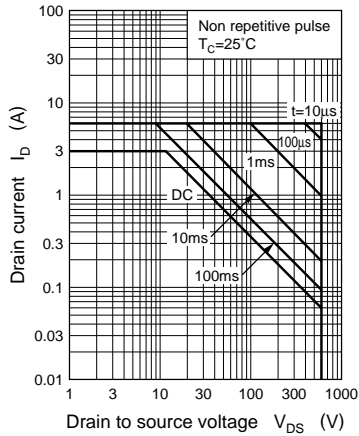
* $L = 5\text{mH}$, $I_L = 3\text{A}$, 1 pulse

■ Electrical Characteristics ($T_C = 25^\circ\text{C}$)

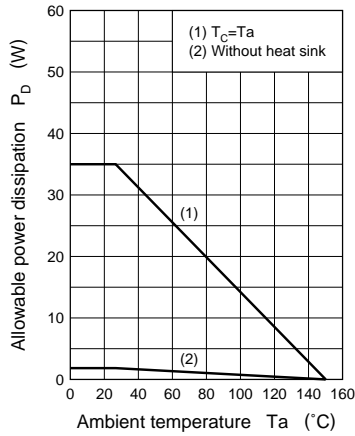
Parameter	Symbol	Conditions	min	typ	max	Unit	
Drain to Source cut-off current	I_{DSS}	$V_{DS} = 480\text{V}$, $V_{GS} = 0$			100	μA	
Gate to Source leakage current	I_{GSS}	$V_{GS} = \pm 30\text{V}$, $V_{DS} = 0$			± 1	μA	
Drain to Source breakdown voltage	V_{DSS}	$I_D = 1\text{mA}$, $V_{GS} = 0$	600			V	
Gate threshold voltage	V_{th}	$V_{DS} = 25\text{V}$, $I_D = 1\text{mA}$	2		5	V	
Drain to Source ON-resistance	$R_{DS(on)}$	$V_{GS} = 10\text{V}$, $I_D = 2\text{A}$		1.7	2.5	Ω	
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = 25\text{V}$, $I_D = 2\text{A}$	1.5	2.5		S	
Diode forward voltage	V_{DSF}	$I_{DR} = 3\text{A}$, $V_{GS} = 0$			-1.5	V	
Input capacitance (Common Source)	C_{iss}	$V_{DS} = 20\text{V}$, $V_{GS} = 0$, $f = 1\text{MHz}$		750		pF	
Output capacitance (Common Source)	C_{oss}				80		pF
Reverse transfer capacitance (Common Source)	C_{rss}				25		pF
Turn-on time (delay time)	$t_{d(on)}$	$V_{DD} = 200\text{V}$, $I_D = 2\text{A}$ $V_{GS} = 10\text{V}$, $R_L = 100\Omega$		15		ns	
Rise time	t_r				25		ns
Turn-off time (delay time)	$t_{d(off)}$				90		ns
Fall time	t_f				40		ns



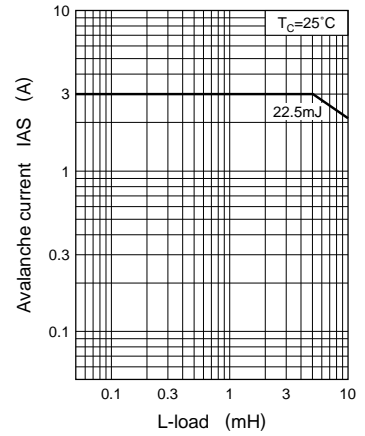
Area of safe operation (ASO)



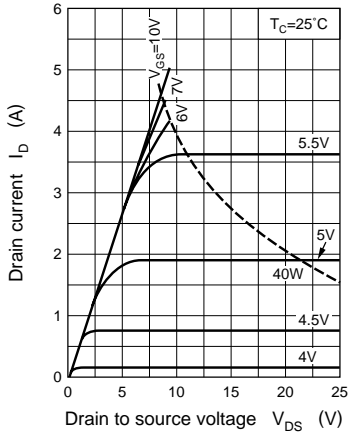
$P_D - T_a$



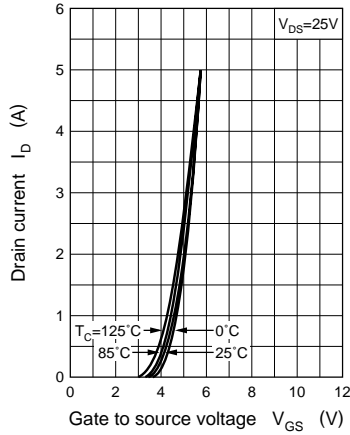
IAS — L-load



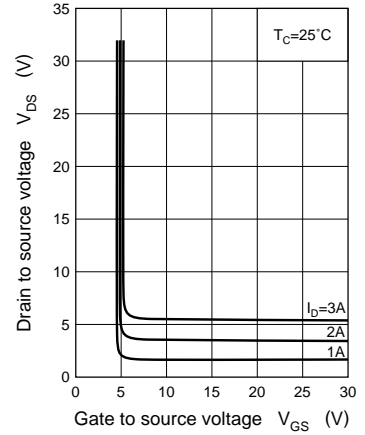
$I_D - V_{DS}$



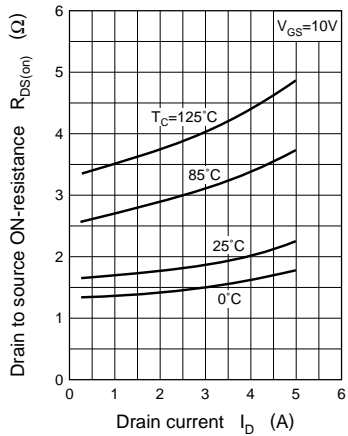
$I_D - V_{GS}$



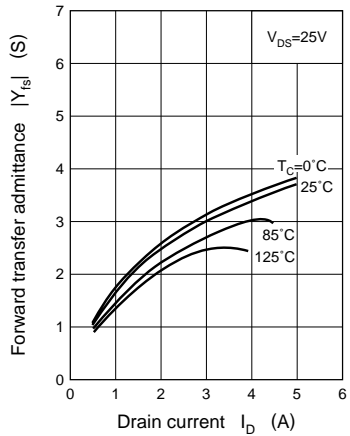
$V_{DS} - V_{GS}$



$R_{DS(on)} - I_D$



$|Y_{fs}| - I_D$



$C_{iss}, C_{oss}, C_{rss} - V_{DS}$

